

Chao Xie

List of Publications by Year in descending order

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78
papers

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citations

66343

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79
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docs citations

79
times ranked

7753
citing authors

#	ARTICLE	IF	CITATIONS
1	Photodetectors Based on Two-Dimensional Layered Materials Beyond Graphene. <i>Advanced Functional Materials</i> , 2017, 27, 1603886.	14.9	534
2	Monolayer Graphene/Germanium Schottky Junction As High-Performance Self-Driven Infrared Light Photodetector. <i>ACS Applied Materials & Interfaces</i> , 2013, 5, 9362-9366.	8.0	347
3	Recent Progress in Solar-Blind Deep-Ultraviolet Photodetectors Based on Inorganic Ultrawide Bandgap Semiconductors. <i>Advanced Functional Materials</i> , 2019, 29, 1806006.	14.9	334
4	Fast, Self-Driven, Air-Stable, and Broadband Photodetector Based on Vertically Aligned PtSe ₂ /GaAs Heterojunction. <i>Advanced Functional Materials</i> , 2018, 28, 1705970.	14.9	314
5	Controlled Synthesis of 2D Palladium Diselenide for Sensitive Photodetector Applications. <i>Advanced Functional Materials</i> , 2019, 29, 1806878.	14.9	286
6	Ultrasensitive broadband phototransistors based on perovskite/organic-semiconductor vertical heterojunctions. <i>Light: Science and Applications</i> , 2017, 6, e17023-e17023.	16.6	272
7	Monolayer Graphene Film on ZnO Nanorod Array for High-Performance Schottky Junction Ultraviolet Photodetectors. <i>Small</i> , 2013, 9, 2872-2879.	10.0	271
8	Flexible Photodetectors Based on Novel Functional Materials. <i>Small</i> , 2017, 13, 1701822.	10.0	259
9	Core-Shell Heterojunction of Silicon Nanowire Arrays and Carbon Quantum Dots for Photovoltaic Devices and Self-Driven Photodetectors. <i>ACS Nano</i> , 2014, 8, 4015-4022.	14.6	258
10	Perovskite-Based Phototransistors and Hybrid Photodetectors. <i>Advanced Functional Materials</i> , 2020, 30, 1903907.	14.9	225
11	Ultrathin and flexible perovskite solar cells with graphene transparent electrodes. <i>Nano Energy</i> , 2016, 28, 151-157.	16.0	200
12	Graphene/Semiconductor Hybrid Heterostructures for Optoelectronic Device Applications. <i>Nano Today</i> , 2018, 19, 41-83.	11.9	172
13	Sensitive Deep Ultraviolet Photodetector and Image Sensor Composed of Inorganic Lead-Free Cs ₃ Cu ₂ I ₅ Perovskite with Wide Bandgap. <i>Journal of Physical Chemistry Letters</i> , 2019, 10, 5343-5350.	4.6	171
14	Ultrafast, Self-Driven, and Air-Stable Photodetectors Based on Multilayer PtSe ₂ /Perovskite Heterojunctions. <i>Journal of Physical Chemistry Letters</i> , 2018, 9, 1185-1194.	4.6	159
15	Light trapping and surface plasmon enhanced high-performance NIR photodetector. <i>Scientific Reports</i> , 2014, 4, 3914.	3.3	132
16	Surface passivation and band engineering: a way toward high efficiency graphene-planar Si solar cells. <i>Journal of Materials Chemistry A</i> , 2013, 1, 8567.	10.3	123
17	High-efficiency graphene/Si nanoarray Schottky junction solar cells via surface modification and graphene doping. <i>Journal of Materials Chemistry A</i> , 2013, 1, 6593.	10.3	122
18	Monolayer graphene film/silicon nanowire array Schottky junction solar cells. <i>Applied Physics Letters</i> , 2011, 99, .	3.3	120

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19	Perovskite/Poly(3-hexylthiophene)/Graphene Multiheterojunction Phototransistors with Ultrahigh Gain in Broadband Wavelength Region. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 1569-1576.	8.0	110
20	High-performance broadband heterojunction photodetectors based on multilayered PtSe ₂ directly grown on a Si substrate. <i>Nanoscale</i> , 2018, 10, 15285-15293.	5.6	102
21	Graphene Transparent Conductive Electrodes for Highly Efficient Silicon Nanostructures-Based Hybrid Heterojunction Solar Cells. <i>Journal of Physical Chemistry C</i> , 2013, 117, 11968-11976.	3.1	96
22	PdSe ₂ Multilayer on Germanium Nanocones Array with Light Trapping Effect for Sensitive Infrared Photodetector and Image Sensing Application. <i>Advanced Functional Materials</i> , 2019, 29, 1900849.	14.9	90
23	Surface induced negative photoconductivity in p-type ZnSe _{0.8} Bi nanowires and their nano-optoelectronic applications. <i>Journal of Materials Chemistry</i> , 2011, 21, 6736.	6.7	89
24	High-efficiency, air stable graphene/Si micro-hole array Schottky junction solar cells. <i>Journal of Materials Chemistry A</i> , 2013, 1, 15348.	10.3	86
25	Recent advances in the fabrication of graphene/ZnO heterojunctions for optoelectronic device applications. <i>Journal of Materials Chemistry C</i> , 2018, 6, 3815-3833.	5.5	85
26	Surface plasmon resonance enhanced highly efficient planar silicon solar cell. <i>Nano Energy</i> , 2014, 9, 112-120.	16.0	83
27	Patterned growth of β -Ga ₂ O ₃ thin films for solar-blind deep-ultraviolet photodetectors array and optical imaging application. <i>Journal of Materials Science and Technology</i> , 2021, 72, 189-196.	10.7	81
28	Aluminium-doped n-type ZnS nanowires as high-performance UV and humidity sensors. <i>Journal of Materials Chemistry</i> , 2012, 22, 6856.	6.7	79
29	One-dimensional CuO nanowire: synthesis, electrical, and optoelectronic devices application. <i>Nanoscale Research Letters</i> , 2014, 9, 637.	5.7	71
30	Schottky solar cells based on graphene nanoribbon/multiple silicon nanowires junctions. <i>Applied Physics Letters</i> , 2012, 100, 193103.	3.3	65
31	High-gain visible-blind UV photodetectors based on chlorine-doped n-type ZnS nanoribbons with tunable optoelectronic properties. <i>Journal of Materials Chemistry</i> , 2011, 21, 12632.	6.7	64
32	Catalyst-Free Vapor-Phase Solid Deposition Growth of β -Ga ₂ O ₃ Nanowires for DUV Photodetector and Image Sensor Application. <i>Advanced Optical Materials</i> , 2019, 7, 1901257.	7.3	62
33	Ferroelectric-Driven Performance Enhancement of Graphene Field-Effect Transistors Based on Vertical Tunneling Heterostructures. <i>Advanced Materials</i> , 2016, 28, 10048-10054.	21.0	58
34	A high-performance near-infrared light photovoltaic detector based on a multilayered PtSe ₂ /Ge heterojunction. <i>Journal of Materials Chemistry C</i> , 2019, 7, 5019-5027.	5.5	58
35	Silicon/Perovskite Core-Shell Heterojunctions with Light-Trapping Effect for Sensitive Self-Driven Near-Infrared Photodetectors. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 27850-27857.	8.0	55
36	TiO ₂ Nanotube Array/Monolayer Graphene Film Schottky Junction Ultraviolet Light Photodetectors. <i>Particle and Particle Systems Characterization</i> , 2013, 30, 630-636.	2.3	53

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37	Graphene-Assisted Growth of Patterned Perovskite Films for Sensitive Light Detector and Optical Image Sensor Application. <i>Small</i> , 2019, 15, e1900730.	10.0	53
38	Inorganic CsBi ₃ /In ₁₀ perovskite/silicon heterojunctions for sensitive, self-driven and air-stable NIR photodetectors. <i>Journal of Materials Chemistry C</i> , 2019, 7, 863-870.	5.5	50
39	Tuning the electrical transport properties of n-type CdS nanowires via Ga doping and their nano-optoelectronic applications. <i>Physical Chemistry Chemical Physics</i> , 2011, 13, 14663.	2.8	47
40	Amplified Spontaneous Emission from Organic-Inorganic Hybrid Lead Iodide Perovskite Single Crystals under Direct Multiphoton Excitation. <i>Advanced Optical Materials</i> , 2016, 4, 1053-1059.	7.3	47
41	Enhanced performance of perovskite/organic-semiconductor hybrid heterojunction photodetectors with the electron trapping effects. <i>Journal of Materials Chemistry C</i> , 2018, 6, 1338-1342.	5.5	47
42	The Effect of Plasmonic Nanoparticles on the Optoelectronic Characteristics of CdTe Nanowires. <i>Small</i> , 2014, 10, 2645-2652.	10.0	43
43	Asymmetric Contact-Induced Self-Driven Perovskite-Microwire Array Photodetectors. <i>Advanced Electronic Materials</i> , 2019, 5, 1900135.	5.1	40
44	Bilayer graphene based surface passivation enhanced nano structured self-powered near-infrared photodetector. <i>Optics Express</i> , 2015, 23, 4839.	3.4	39
45	p-CdTe nanoribbon/n-silicon nanowires array heterojunctions: photovoltaic devices and zero-power photodetectors. <i>CrystEngComm</i> , 2012, 14, 7222.	2.6	38
46	Ultrahigh Mobility of p-Type CdS Nanowires: Surface Charge Transfer Doping and Photovoltaic Devices. <i>Advanced Energy Materials</i> , 2013, 3, 579-583.	19.5	37
47	Self-Powered Filterless Narrow-Band n Heterojunction Photodetector for Low Background Limited Near-Infrared Image Sensor Application. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 21845-21853.	8.0	37
48	Defect-induced broadband photodetection of layered In ₂ Se ₃ nanofilm and its application in near infrared image sensors. <i>Journal of Materials Chemistry C</i> , 2019, 7, 11532-11539.	5.5	36
49	Nano-Schottky barrier diodes based on Sb-doped ZnS nanoribbons with controlled p-type conductivity. <i>Applied Physics Letters</i> , 2011, 98, .	3.3	35
50	Polymeric Carbon Nitride Nanosheets/Graphene Hybrid Phototransistors with High Responsivity. <i>Advanced Optical Materials</i> , 2016, 4, 555-561.	7.3	35
51	A Highly Sensitive Perovskite/Organic Semiconductor Heterojunction Phototransistor and Its Device Optimization Utilizing the Selective Electron Trapping Effect. <i>Advanced Optical Materials</i> , 2019, 7, 1900272.	7.3	35
52	ZnSe nanoribbon/Si nanowire n heterojunction arrays and their photovoltaic application with graphene transparent electrodes. <i>Journal of Materials Chemistry</i> , 2012, 22, 22873.	6.7	32
53	A SERS stamp: Multiscale coupling effect of silver nanoparticles and highly ordered nano-micro hierarchical substrates for ultrasensitive explosive detection. <i>Sensors and Actuators B: Chemical</i> , 2020, 321, 128543.	7.8	31
54	Opening the Band Gap of Graphene via Fluorination for High-Performance Dual-Mode Photodetector Application. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 21702-21710.	8.0	28

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55	Doping dependent crystal structures and optoelectronic properties of n-type CdSe:Ga nanowires. <i>Nanoscale</i> , 2011, 3, 4798.	5.6	27
56	Construction of PtSe ₂ /Ge heterostructure-based short-wavelength infrared photodetector array for image sensing and optical communication applications. <i>Nanoscale</i> , 2021, 13, 7606-7612.	5.6	27
57	Highly Sensitive Narrowband Si Photodetector With Peak Response at Around 1060 nm. <i>IEEE Transactions on Electron Devices</i> , 2020, 67, 3211-3214.	3.0	26
58	Surface charge transfer induced p-CdS nanoribbon/n-Si heterojunctions as fast-speed self-driven photodetectors. <i>Journal of Materials Chemistry C</i> , 2015, 3, 6307-6313.	5.5	24
59	Fabrication of Addressable Perovskite Film Arrays for High-Performance Photodetection and Real-Time Image Sensing Application. <i>Journal of Physical Chemistry Letters</i> , 2021, 12, 2930-2936.	4.6	23
60	Lasing Characteristics of CH ₃ NH ₃ PbCl ₃ Single-Crystal Microcavities under Multiphoton Excitation. <i>Advanced Optical Materials</i> , 2018, 6, 1700992.	7.3	22
61	Multilayered PtSe ₂ /pyramid-Si heterostructure array with light confinement effect for high-performance photodetection, image sensing and light trajectory tracking applications. <i>Journal of Materials Chemistry C</i> , 2021, 9, 2823-2832.	5.5	20
62	High-performance nonvolatile Al _x O _y /CdTe:Sb nanowire memory device. <i>Nanotechnology</i> , 2013, 24, 355203.	2.6	19
63	Multilayered PdTe ₂ /GaN Heterostructures for Visible-Blind Deep-Ultraviolet Photodetection. <i>IEEE Electron Device Letters</i> , 2021, 42, 1192-1195.	3.9	18
64	Chlorine-Doped ZnSe Nanoribbons with Tunable n-Type Conductivity as High-Gain and Flexible Blue/UV Photodetectors. <i>ChemPlusChem</i> , 2012, 77, 470-475.	2.8	15
65	Electrically adjusted deep-ultraviolet/near-infrared single-band/dual-band imaging photodetectors based on Cs ₃ Cu ₂ I ₅ /PdTe ₂ /Ge multiheterostructures. <i>Journal of Materials Chemistry C</i> , 2021, 9, 14897-14907.	5.5	14
66	Photodetectors: Controlled Synthesis of 2D Palladium Diselenide for Sensitive Photodetector Applications (<i>Adv. Funct. Mater.</i> 1/2019). <i>Advanced Functional Materials</i> , 2019, 29, 1970005.	14.9	13
67	Controlled synthesis of GaSe microbelts for high-gain photodetectors induced by the electron trapping effect. <i>Journal of Materials Chemistry C</i> , 2020, 8, 5375-5379.	5.5	12
68	High-performance light trajectory tracking and image sensing devices based on a β -In ₂ Se ₃ /GaAs heterostructure. <i>Journal of Materials Chemistry C</i> , 2020, 8, 13762-13769.	5.5	11
69	Ti ₃ C ₂ T _x MXene/Ge 2D/3D van der Waals heterostructures as highly efficient and fast response near-infrared photodetectors. <i>Applied Physics Letters</i> , 2022, 120, .	3.3	11
70	Characterization of structural transitions and lattice dynamics of hybrid organic-inorganic perovskite CH ₃ NH ₃ PbI ₃ *. <i>Chinese Physics B</i> , 2019, 28, 076102.	1.4	10
71	Dual-plasmonic Au/graphene/Au-enhanced ultrafast, broadband, self-driven silicon Schottky photodetector. <i>Nanotechnology</i> , 2018, 29, 505203.	2.6	9
72	High-Performance Blue-Light Photodetectors Based on Single-Crystal ZnSe Nanoribbons with Controlled Gallium Doping. <i>Science of Advanced Materials</i> , 2012, 4, 332-336.	0.7	9

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73	Ultrawide-Bandgap Semiconductors: Recent Progress in Solar-Blind Deep-Ultraviolet Photodetectors Based on Inorganic Ultrawide Bandgap Semiconductors (Adv. Funct. Mater. 9/2019). Advanced Functional Materials, 2019, 29, 1970057.	14.9	8
74	Enhanced Light Trapping in Conformal CuO/Si Microholes Array Heterojunction for Self-Powered Broadband Photodetection. IEEE Electron Device Letters, 2021, 42, 883-886.	3.9	7
75	Distinguishing wavelength using two parallelly stacking graphene/thin Si/graphene heterojunctions. Journal of Materials Chemistry C, 0, , .	5.5	6
76	Photodetectors: Fast, Self-Driven, Air-Stable, and Broadband Photodetector Based on Vertically Aligned PtSe ₂ /GaAs Heterojunction (Adv. Funct. Mater. 16/2018). Advanced Functional Materials, 2018, 28, 1870106.	14.9	5
77	A quasi-2D perovskite antireflection coating to boost the performance of multilayered PdTe ₂ /Ge heterostructure-based near-infrared photodetectors. Journal of Materials Chemistry C, 2022, 10, 6025-6035.	5.5	5
78	Fabrication of a $\text{In}_2\text{Se}_3/\text{Si}$ heterostructure phototransistor for heart rate detection. Journal of Materials Chemistry C, 0, , .	5.5	4